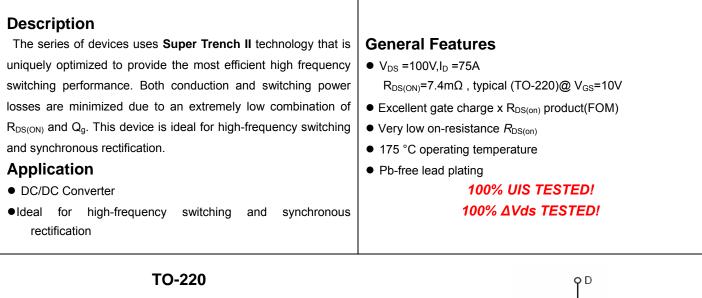
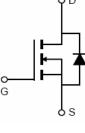


NCE N-Channel Super Trench II Power MOSFET







Schematic Diagram

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP080N10	NCEP080N10	TO-220	-	-	-

Absolute Maximum Ratings (T_c=25[°]C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	100	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	Ι _D	75	А
Drain Current-Continuous(Tc=100℃)	I _D (100℃)	58	A
Pulsed Drain Current	I _{DM}	300	A
Maximum Power Dissipation	PD	120	W
Derating factor		0.8	W/°C
Single pulse avalanche energy (Note 4)	E _{AS}	420	mJ
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 175	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Case	R _{eJC}	1.25	°C/W	
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Electrical Characteristics (T_c=25 $^{\circ}$ C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	· ·		·			•
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	100		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	±100	nA
On Characteristics (Note 3)	· ·		·			•
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_D=250\mu A$	2.0	3.0	4.0	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =37.5A	-	7.4	8.0	mΩ
Forward Transconductance	g fs	V _{DS} =5V,I _D =37.5A		60	_	S
Dynamic Characteristics (Note3)			•	•		
Input Capacitance	C _{lss}		-	3070	-	pF
Output Capacitance	C _{oss}	V _{DS} =50V,V _{GS} =0V, F=1.0MHz	-	290	_	pF
Reverse Transfer Capacitance	C _{rss}			23	-	pF
Switching Characteristics (Note 3)						
Turn-on Delay Time	t _{d(on)}		-	15	-	nS
Turn-on Rise Time	tr	V _{DD} =50V,I _D =37.5A	-	10	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{G} =1.6 Ω	-	34	-	nS
Turn-Off Fall Time	t _f		-	8	-	nS
Total Gate Charge	Qg		-	53	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =50V,I _D =37.5A, V _{GS} =10V	-	18	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} -10V	-	16	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 2)	V _{SD}	V _{GS} =0V,I _S =37.5A	-	-	1.2	V
Diode Forward Current	Is		-	-	75	А
Reverse Recovery Time	t _{rr}	$T_J = 25^{\circ}C, I_F = 37.5A$	-	60	-	nS
Reverse Recovery Charge	Qrr	di/dt = $100A/\mu s^{(Note3)}$	-	106	-	nC

Notes:

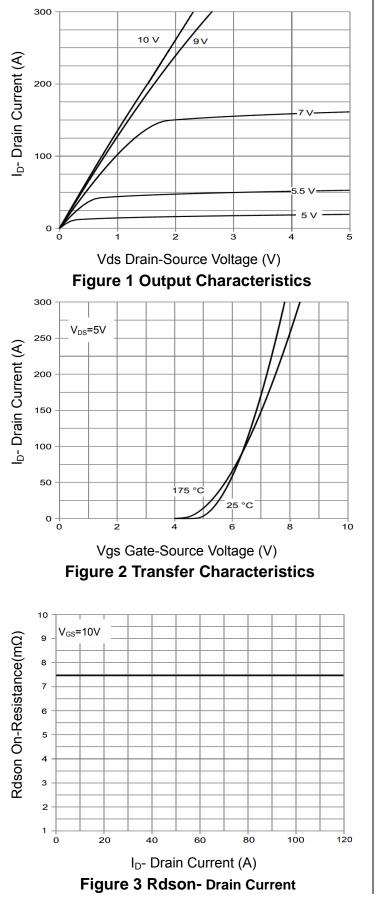
1. Repetitive Rating: Pulse width limited by maximum junction temperature.

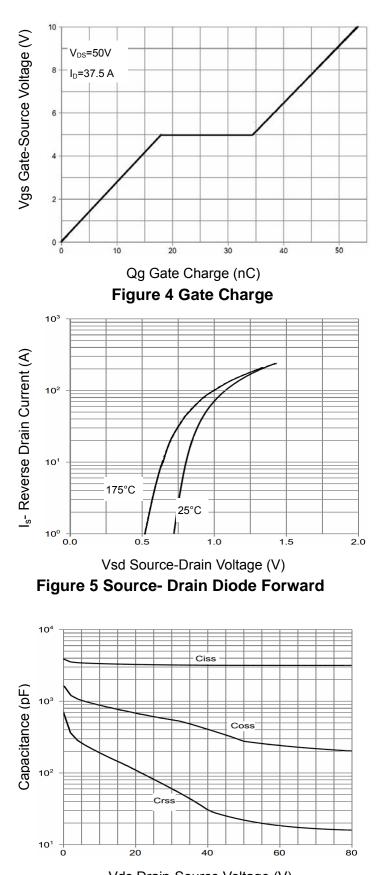
2. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

3. Guaranteed by design, not subject to production 4. EAS condition : Tj=25°C,V_{DD}=50V,V_G=10V,L=0.25mH,Rg=25 Ω





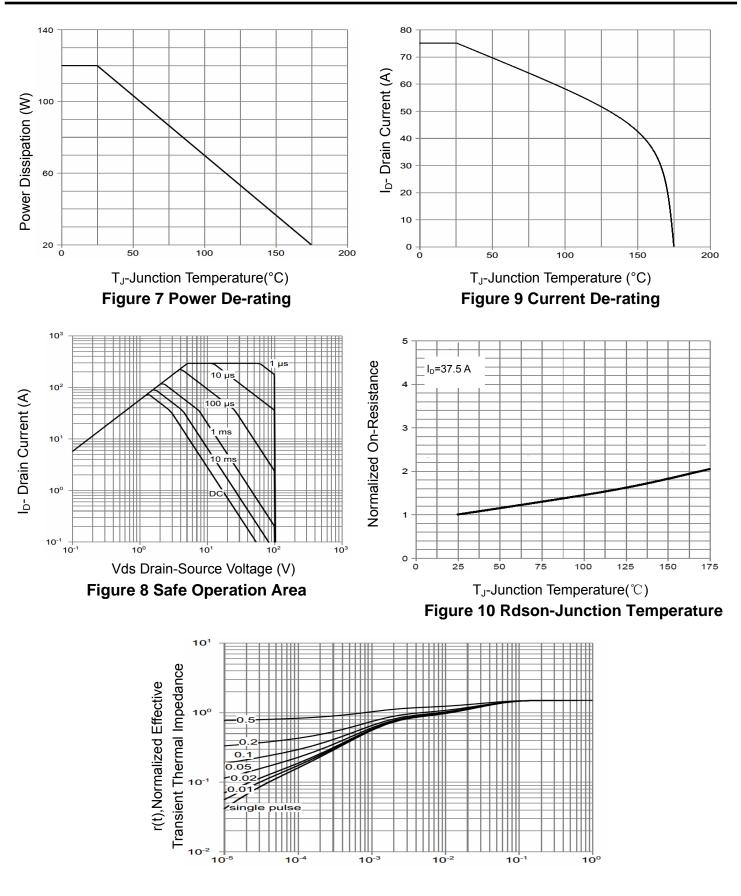




Vds Drain-Source Voltage (V) Figure 6 Capacitance vs Vds



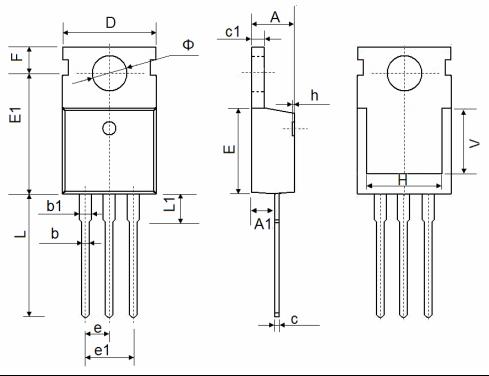
NCEP080N10



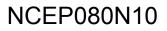
Square Wave Pluse Duration(sec) Figure 11 Normalized Maximum Transient Thermal Impedance



TO-220-3L Package Information



Cumhal	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
E	8.9500	9.750	0.352	0.384	
E1	12.650	12.950	0.498	0.510	
е	2.540 TYP.		0.100 TYP.		
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	6.900 REF.		0.276 REF.		
Φ	3.400	3.800	0.134	0.150	



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